

SANYO Semiconductors DATA SHEET

MCH3217— NPN Epitaxial Planar Silicon Transistor

DC / DC Converter Applications

Applications

· Relay drivers, lamp drivers, motor drivers, flash.

Features

- · Adoption of MBIT processes.
- · Large current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- Narrow hFE range.
- Ultrasmall package facilitates miniaturization in end products (mounting height: 0.85mm).
- · High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		15	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	Ic		1.5	Α
Collector Current (Pulse)	ICP		3	Α
Base Current	IB		300	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm²X0.8m)	0.7	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oille
Collector Cutoff Current	ICBO	V _{CB} =12V, I _E =0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			0.1	μΑ
DC Current Gain	hFE	V _{CE} =2V, I _C =100mA	250		400	
Gain-Bandwidth Product	fT	V _{CE} =2V, I _C =300mA		430		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		9.5		pF

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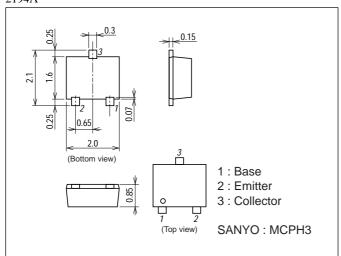
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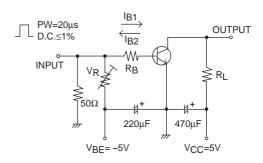
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=750mA, IB=15mA		80	120	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =750mA, I _B =15mA		0.83	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =10μA, I _C =0	6			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		160		ns
Fall Time	tf	See specified Test Circuit.		15		ns

Package Dimensions

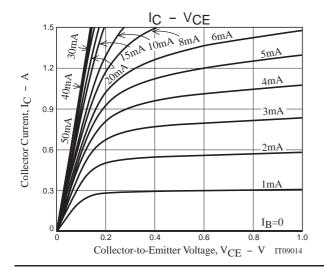
unit : mm 2194A

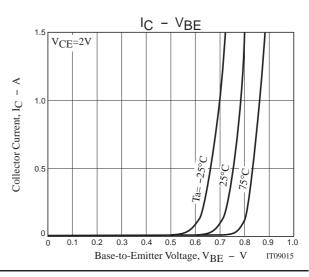


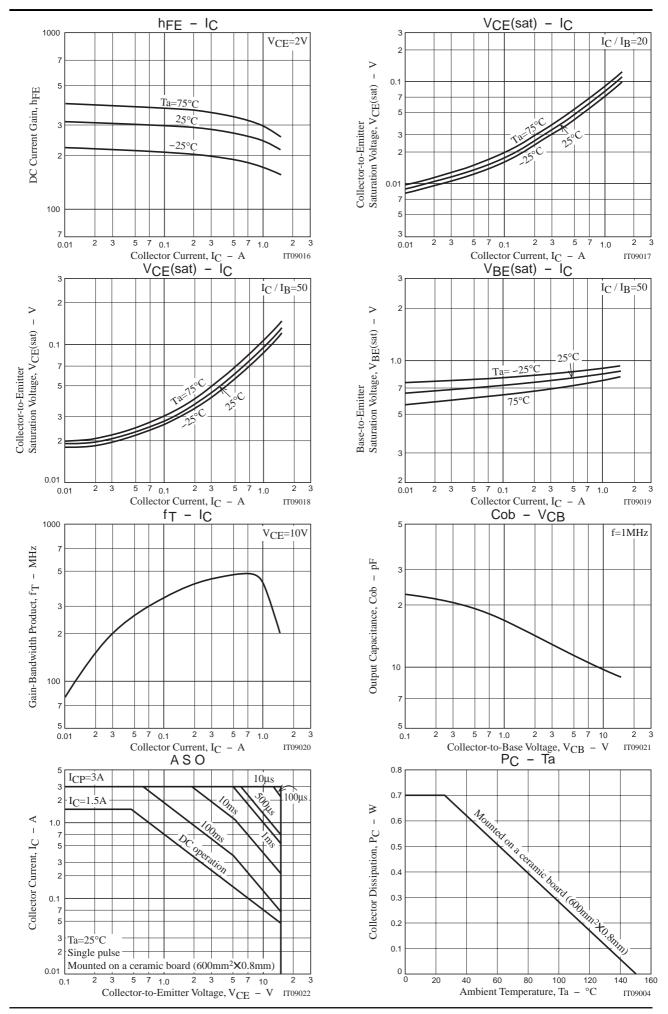
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=750mA$







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